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Docket No.: 195425US0

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ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

RE: Application Serial No.:

Applicants: Jianmin QIAO Filing Date: 09/654,078

For: DUAL DAMASCENE STRUCTURE

AND METHOD OF MAKING

Group Art Unit: 2814 Examiner: PHAM, H.

SIR:

Attached hereto for filing are the following papers:

RESTRICTION RESPONSE

Our check in the amount of \$-0- is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,

MAIER & NEUSTADT, P.C.

Richard L. Chinn, Ph.D.

Attorney of Record

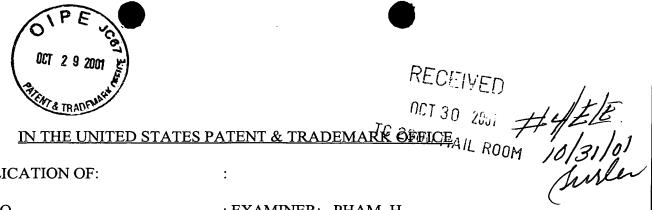
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195425US0



IN RE APPLICATION OF:

Jianmin QIAO : EXAMINER: PHAM, H.

SERIAL NO.: 09/654,078

FILED: SEPTEMBER 1, 2000 : GROUP ART UNIT: 2814

FOR: DUAL DAMASCENE STRUCTURE:

AND METHOD OF MAKING

RESTRICTION RESPONSE

ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

SIR:

Responsive to the Restriction Requirement of September 28, 2001, Applicants elect, Group I, Claims 1-10, directed to a semiconductor device, with traverse.

REMARKS

The Examiner has characterized the claim invention as follows:

Group I: Claims 1-10, directed to a semiconductor device;

Group II: Claims 11-17, directed to a method of making a semiconductor device.

Restriction is only proper if the claims of the restricted groups are independent or patentably distinct and there would be a serious burden placed on the examiner if restriction is